CMKDM8005

SURFACE MOUNT SILICON DUAL P-CHANNEL ENHANCEMENT-MODE MOSFET

SOT-363 CASE

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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMKDM8005 consists of dual P-Channel enhancement-mode silicon MOSFETs designed for high speed pulsed amplifier and driver applications. These MOSFETs offer very low $r_{DS(ON)}$ and low threshold voltage.

MARKING CODE: C85M

APPLICATIONS:

- Load switch/Level shifting
- Battery charging
- Boost switch
- Electro-luminescent backlighting

FEATURES:

- ESD protection up to 1800V (Human Body Model)
- 350mW power dissipation
- Very low $r_{DS(ON)}$
- Low threshold voltage
- Logic level compatible
- Small, SOT-363 surface mount package

MAXIMUM RATINGS: (T_A=25°C)	**SYMBOL**		**UNITS**
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	8.0	V
Continuous Drain Current (Steady State)	I_D	650	mA
Continuous Source Current (Body Diode)	I_S	250	mA
Maximum Pulsed Drain Current	I_{DM}	1.0	A
Power Dissipation	P_D	350	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	357	°C/W

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: (T_A=25°C unless otherwise noted)

SYMBOL	**TEST CONDITIONS**	**MIN**	**TYP**	**MAX**	**UNITS**
I_{GSSF}, I_{GSSR}	V_{GS}=4.5V, V_{DS}=0			10	μA
I_{DSS}	V_{DS}=16V, V_{GS}=0			100	nA
BV_{DSS}	V_{GS}=0, I_D=250μA	20			V
$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	0.5		1.0	V
V_{SD}	V_{GS}=0, I_S=250mA			1.1	V
$r_{DS(ON)}$	V_{GS}=4.5V, I_D=350mA		0.25	0.36	Ω
$r_{DS(ON)}$	V_{GS}=2.5V, I_D=300mA		0.37	0.5	Ω
$r_{DS(ON)}$	V_{GS}=1.8V, I_D=150mA			0.8	Ω
g_{FS}	V_{DS}=10V, I_D=200mA	0.2			S
C_{rss}	V_{DS}=16V, V_{GS}=0, f=1.0MHz		25		pF
C_{iss}	V_{DS}=16V, V_{GS}=0, f=1.0MHz		100		pF
C_{oss}	V_{DS}=16V, V_{GS}=0, f=1.0MHz		21		pF

R3 (3-June 2013)

CMKDM8005

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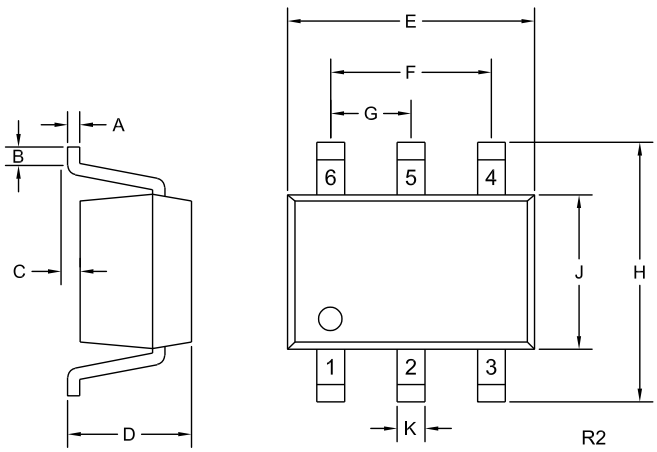
ELECTRICAL CHARACTERISTICS PER TRANSISTOR - Continued: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
$Q_{g(tot)}$	V_{DS}=10V, V_{GS}=4.5V, I_D=200mA	1.2		nC
Q_{gs}	V_{DS}=10V, V_{GS}=4.5V, I_D=200mA	0.24		nC
Q_{gd}	V_{DS}=10V, V_{GS}=4.5V, I_D=200mA	0.36		nC
t_{on}	V_{DD}=10V, V_{GS}=4.5V, I_D=200mA, R_G=10Ω	38		ns
t_{off}	V_{DD}=10V, V_{GS}=4.5V, I_D=200mA, R_G=10Ω	48		ns

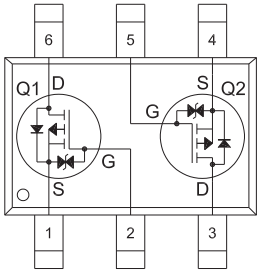
SOT-363 CASE - MECHANICAL OUTLINE



DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0.004	0.010	0.10	0.25
B	0.005	-	0.12	-
C	0.000	0.004	0.00	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.075	0.091	1.90	2.30
J	0.043	0.055	1.10	1.40
K	0.006	0.012	0.15	0.30

SOT-363 (REV: R2)

PIN CONFIGURATION



LEAD CODE:
1) Source Q1
2) Gate Q1
3) Drain Q2
4) Source Q2
5) Gate Q2
6) Drain Q1

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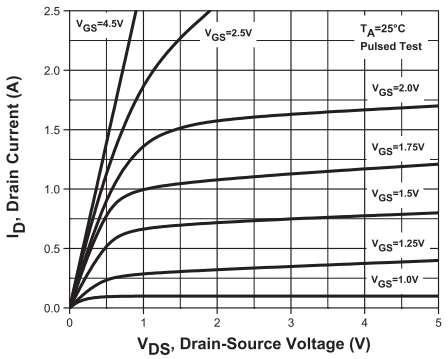
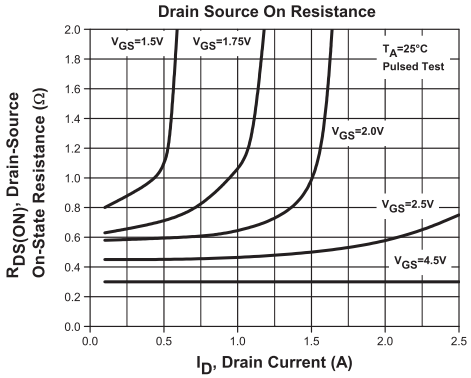
TYPICAL ELECTRICAL CHARACTERISTICS

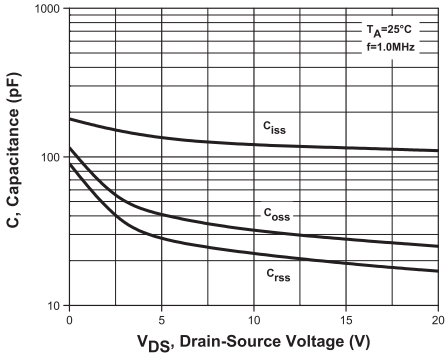
Output Characteristics



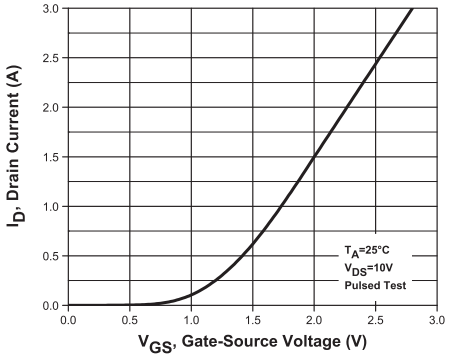
Drain Source On Resistance



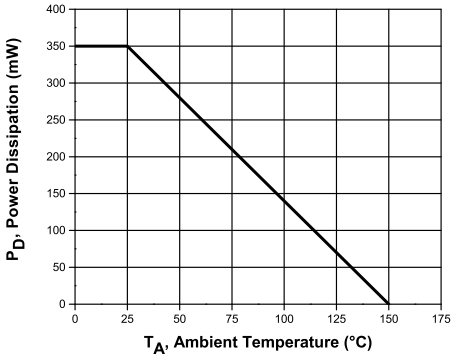
Capacitance



Transfer Characteristics



Power Derating



R3 (3-June 2013)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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